NSN 5962-01-420-7500

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View Online at https://aerobasegroup.com/nsn/5962-01-420-7500

Body Length:	
0.358 inches	
Body Width:	
0.358 inches	
Body Height:	
0.100 inches	
Maximum Powe	er Dissipation Rating:
500.0 milliwatts	
Operating Tem	purature Range:
-55.0/+125.0 de	grees celsius
Storage Tempu	irature Range:
-65.0/+150.0 de	grees celsius
End Applicatio	n:
Pacer dawn	
Features Provid	ded:
Hermetically sea	aled and burn in and programmable and positive outputs and electrostatic sensitive
Inclosure Mate	rial:
Ceramic and gla	ISS
Inclosure Conf	iguration:
Leadless flat page	ck
Output Logic F	orm:
Transistor-transi	istor logic
Input Circuit Pa	attern:
12 input	
Criticality Code	a Justification:
Cbbl	
Case Outline S	ource And Designator:
C-2 mil-m-38510	
Terminal Surfa	ce Treatment:
Solder	
Product Name:	
Program instruc	tion (pal16r6a-2)
Voltage Rating	And Type Per Characteristic:
-0.5 volts power	r source and 7.0 volts power source
Time Rating Pe	r Chacteristic:
50.00 nanoseco	nds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	е Туре:
Pal	
Special Feature	es:
Altered item m	ade from device 81036132x, cage 67268, program p/n 7816354p634 microcircuits, memory, programmable logic,

Altered item, made from device 81036132x, cage 67268, program p/n 7816354p634 microcircuits, memory, programmable logic, monolithic silicon

Test Data Document:

96906-mill-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type And Quantity:

20 leadless

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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